NMOS Max Sweep

--- Operating Point ---

V(vd): 3.17012 voltage

V(vg): 1.3 voltage

V(n001): 5 voltage

Id(M1): 0.000844822 device\_current

Ig(M1): 0 device\_current

Ib(M1): -3.18602e-012 device\_current

Is(M1): -0.000844822 device\_current

I(Rd): 0.000844822 device\_current

I(Vdd): -0.000844822 device\_current

I(Vin): 0 device\_current

PMOS Max Sweep

--- Operating Point ---

V(n001): 5 voltage

V(vin): 3.66 voltage

V(vout): 2.37239 voltage

Id(M1): -0.000550439 device\_current

Ig(M1): 0 device\_current

Ib(M1): 2.62314e-012 device\_current

Is(M1): 0.000550439 device\_current

I(R1): 0.000550439 device\_current

I(V2): -0.000550439 device\_current

I(V1): 0 device\_current

NMOS Max gain

--- Operating Point ---

V(vin): 1.18 voltage

V(n001): 1.2 voltage

V(vout): 0.52626 voltage

Id(M1): 0.000536417 device\_current

Ig(M1): 0 device\_current

Ib(M1): -5.40102e-013 device\_current

Is(M1): -0.000536417 device\_current

I(R1): 0.000536417 device\_current

I(V2): -0.000536417 device\_current

I(V1): 0 device\_current